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A NEUROMORPHIC SELECTIVE ATTENTION ARCHITECTURE WITH DYNAMIC SYNAPSES AND INTEGRATE-AND-FIRE NEURONS

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ABSTRACT

Selective attention is a process widely used by biological sensory systems to overcome the problem of limited parallel processing capacity: salient subregions of the input stimuli are serially processed, while non–salient regions are suppressed. We present an analog Very Large Scale Integration implementation of a building block for a multi–chip neuromorphic hardware model of selective attention. We describe the chip's architecture underlining the similarity between the circuits and biological neurons and synapses. We plan to present experimental results that explore the dynamics of the system varying its bias settings corresponding to physiological properties of neurons and synapses.

INTRODUCTION

Selective attention is one of the most powerful strategies used by biological systems, from which robotics and in general all artificial computation can take advantage. In a biological sensory system, selective attention acts as a dynamical filter that selects the most salient regions of the input, sequentially allocating computational resources, for analyzing the target. This strategy limits the computational demand respect to parallel processing. The selection of one between possible targets depends on its 'saliency'; the saliency of a stimulus depends on its physical and semantic characteristics and on the relevance it has for the ongoing activity of the subject. There are two main pathways that determine the emergence of one 'winning' stimulus in the competition for saliency: one is stimulus-driven, bottom-up and task-independent, the other is goal-dependent, and acts in a slower top-down manner.

Much of the research focused on modelling the bottom-up aspect of selective attention, gave rise to software [1–4] and hardware models [5–8] based on the concept of *saliency map* [9]. Software models based on this concept account for many psychophysical and neurophysiological observations [10] and have features that could be used in practical applications. Hardware implementations of selective attention systems have the additional advantage of real time computation and compactness: they can be used for building artificial systems that interact with real world stimuli in real time, and can therefore be a powerful tool for studying computational properties of different types of selective attention models.

The concrete physical realization of these models has to take into account issues such as noise, limited resources and power availability, as well as fault tolerance, and robustness to variations in the input, very much like the brain has to. This will hopefully lead to a better understanding of the physical and computational mechanisms used by the brain to solve these problems, including details that might be overlooked in abstract models or computer simulations.

Here we present a VLSI device, the Selective Attention Chip (SAC), that can be used as a building block for hardware multi-chip sensory systems, based on selective attention models. Specifically the SAC represent a hardware implementation of a saliency-based computational model of the bottom-up dynamical form of selective attention [11]. The SAC was realized with Very Large Scale of Integration (VLSI) technology using neuro-

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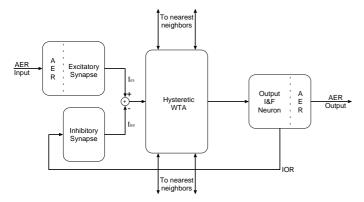


Figure 1. Block diagram of a basic cell of the 32×32 selective attention architecture.

morphic circuits that directly map biophysical neuronal properties onto silicon. It employs a spike-based representation both for receiving input signals and for transmitting output signals to further processing stages. Its input signals are expected to arrive from a saliency map, topographically encoding local conspicuousness over the entire visual scene. Its output signals can be used in real time to drive motors of active vision systems or to select subregions of images captured from wide field-of-view cameras.

This chip is the evolution of a similar device previously proposed in [12]. This new device augments the previous one by implementing a larger array (32×32 cells as opposed to 8×8), by using a novel low-power spiking neuron circuit [13], and by using more advanced synaptic circuits with realistic dynamics and adaptation properties [14, 15].

In the next sections we describe the chip's architecture and its main circuital elements and show behavioral simulation results that illustrate the effects of the new types of synapses and neurons on the selective attention dynamics.

THE SAC ARCHITECTURE

The SAC was fabricated using a standard $0.35\mu m$ CMOS technology, it contains an array of 32×32 cells, laid out on a square grid, each cell is $50.65 \times 32\mu m^2$ and the whole array occupies an area of $23447\mu m^2$. Each cell in the bidimensional array comprises an input circuit that models the dynamics of a biological excitatory synapse, generating Excitatory Post–Synaptic Currents (EPSCs), a hysteretic Winner–Take–All (WTA) competitive element [16], an output Integrate and Fire (I&F) neuron [13] and a feedback inhibitory synapse (see Fig. 1).

Input and output signals of the SAC are asynchronous digital pulses (spikes) that use an *Address Event Representation* (AER) [17]. The AER is inspired by cortical communication: it is based on asynchronous events (spikes) that encode the address of the sending neuron and carry the analog information in their temporal structure. This protocol allows multiple AER chips to communicate using spikes, just like the cortex, and can be used in multi–chip systems, with multiple senders and multiple receivers [18,19]. Using this representation the SAC can exchange data, while processing signals in parallel, in real time [12]. The communication protocol used and the SAC's bidimensional architecture make it particularly suitable for processing visual inputs coming from artificial spiking retinas or cochleas.

Input spikes arriving for example from a silicon retina [20] or from a software based vision system [8] are integrated by the excitatory synapses of the array into excitatory analog current (see I_{ex} of Fig.1); the effect of a single spike on the integrated current depends on the synaptic weight V_w of Fig. 2(a). The initial weight of the synapse is set by an external voltage reference (V_{w0} of Fig. 2(a)), then as the synapse receives spikes (voltage pulses *pre*) the effective synaptic weight V_w decreases, in a way to model local gain control, reproducing *short time depression* dynamics observed in physiological recordings [21].

The integrated excitatory current is sourced into the correspondent WTA cell that competes with the other cells by means of lateral excitatory and inhibitory connections. The spatial extent of the competition can be set by the strength of these lateral connections; in particular we can set global competition, allowing only one cell to win, or we can have local competition, with multiple spatially distant winners [16].

As soon as a WTA cell wins the competition it sources a fixed amount of current into the membrane capacitance of the adaptive low power I&F neuron. The spiking frequency of the I&F neuron is monotonic with its input current. The adaptation neuron's mechanism decreases the neuron's firing rate with time [13].

The output spikes go to an arbitration circuit that sends the address of the winning pixel to the AER bus and, in parallel, to the corresponding inhibitory synapse that is responsible for generating the inhibitory current I_{ior} (see Fig.1); this current is subtracted from the input excitatory current I_{ex} , therefore the net input current to the winning cell decreases until a different cell is eventually selected as winner. This negative feedback mechanism is known as Inhibition of Return (IOR), it allows the network to deselect the winning cell and switch between inputs with different salience.

The SAC has been designed with tunable parameters that allow to modify the strength of synaptic contributions, the dynamics of synaptic short term depression and of neuronal adaptation, as well as the spatial extent of competition and the dynamics of IOR. All these parameters enrich the dynamics of the network that can be exploited to model the complex selective attention scan path.

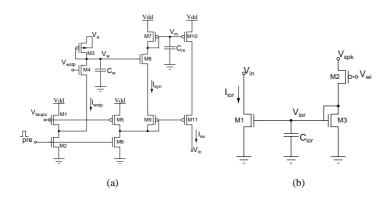


Figure 2. (a) Excitatory synapse circuit. Input spikes are applied to M1, and transistor M11 outputs the integrated excitatory current I_{ex} . (b) Inhibitory synapse circuit. Spikes from the local output neurons are integrated into an inhibitory current I_{inh} .

BEHAVIORAL SIMULATIONS

In order to assess the dynamical properties added by synaptic short term depression and spiking frequency adaptation, we simulated the behaviour of 2 pixels, using the analitical equations that describe the circuits.

Excitatory Synapse

The current mirror integrator circuit [22] in the excitatory synapse integrates the incoming spikes, decreasing the gate voltage V_m of the output transistor. We can derive the time course of V_m during the spike from Kirchoff's current law and from the transistor's weak inversion equations:

$$I_{syn} = -C_m \frac{dV_m}{dt} + I_{0_p} e^{\frac{\kappa (V_{dd} - V_m)}{U_T}}$$
(1)

Where I_{0_p} is the transistor's dark current, U_T is the termal voltage, κ is the transistor subthreshold slope factor and V_{dd} is the power supply. Integrating Eq. 1:

$$V_m(t) = \frac{U_T}{\kappa} \ln\left(\left(e^{\frac{\kappa V_{m0}}{U_T}} - \frac{I_{0_p}}{I_{syn}} e^{\frac{\kappa V_{dd}}{U_T}} \right) e^{-\frac{\kappa I_{syn}}{U_T C_m}t} + \frac{I_{0_p}}{I_{syn}} e^{\frac{\kappa V_{dd}}{U_T}} \right) \quad (2)$$

During a spike the voltage V_m is decreased by an amount determined by I_{syn} that depends exponentially on the synaptic weight V_w . The short term depressing part of the synapse (transistors M1 - -M4) of Fig. 2(a) decreases V_w with each spike. To a first order approximation during a spike the synaptic weight decreases linearly:

$$V_w(t) = V_{w0} - \frac{I_{wstp}}{C_w}t \tag{3}$$

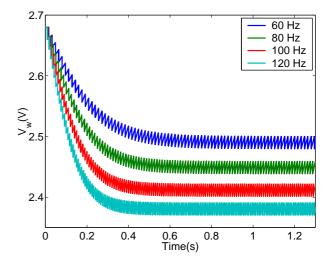


Figure 3. Short term depression of the excitatory synapse, the weight of the synapse, Vw, is plotted for input spike trains of different frequency. Higher the frequency, lower is the depressed value.

During the time interval between spikes transistors *M*3 and *M*7 in the synapse of Fig. 2 tend to restore V_w and V_m respectively. In this case the synapse has no input and V_m can be obtained integrating Eq. 1, for $I_{syn} = 0$:

$$V_m(t) = \frac{U_T}{\kappa} \ln\left(e^{\frac{\kappa V_{m0}}{U_T}} + \frac{\kappa I_{0_p}}{U_T C_m} e^{\frac{\kappa V_{dd}}{U_T}}t\right)$$
(4)

In the same way V_w is obtained integrating $\frac{dV_w}{dt} = \frac{I_{M1}}{C_w}$:

$$V_w(t) = \frac{U_T}{\kappa} \ln \frac{\kappa I_{0_p}}{U_T C_w} e^{\frac{\kappa V_a}{U_T}} t + e^{\frac{\kappa V_w 0}{U_T}}$$
(5)

In Fig. 3 we show the variation of the synaptic weight V_w when the synapse is stimulated with constant spike trains for increasing input firing rates, the steady state of depression decreases with spiking frequency of the input.

WTA

The hysteretic WTA cell compares its input current to the current of the winning cell plus an hysteretic current I_{hyst} ; the hysteretic current gives to the currently winning cell a competitive advantage, implementing a sort of short time memory that could be useful for tracking salient patterns. The input current to the WTA cell is the sum of the positive current sourced by the excitatory input synapse I_{ex} , and the negative current subtracted by the IOR inhibitory synapse I_{ior} . The effect of the WTA on the two pixels network we simulated is shown in Fig. 4, the activity of the two output neurons alternates indicating which pixel is winning the competition for saliency.

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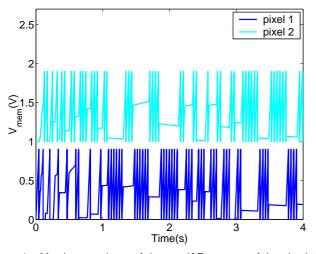


Figure 4. Membrane voltage of the two I&F neurons of the simulated network. The WTA switches between the two neurons: when one is spiking, the other is silent. One neuron wins for a certain temporal interval that is determined by the relative stimulus strength, the dynamics of IOR and the value of the hysteretic current.

I&F neuron

The I&F neuron integrates its input current untill the integrated membrane voltage crosses a threshold. At that point the neuron generates a spike and the membrane voltage is reset (see Fig. 4). We can model the subthreshold time course of V_{mem} by:

$$C_{mem}\frac{d}{dt}V_{mem} = I_{wta} - I_{leak} + I_{fb} - I_{adap}$$
(6)

where the net current in input is given by the current sourced by the WTA cell I_{wta} , minus a leakage current

$$I_{leak} = I_{0_n} e^{\frac{\kappa}{U_T} V_{lk}} \left(1 - e^{-\frac{V_{mem}}{U_T}}\right)$$
(7)

a feedback current

$$I_{fb} = I_1 e^{-\kappa^2 \frac{V_{sf}}{U_T}} e^{\kappa^2 \frac{V_{mem}}{U_T}}$$
(8)

and an adaptive current that increases for each spike,

$$I_{adap} = I_0 e^{\kappa \frac{V_{a0}}{U_T}} e^{\kappa \gamma \frac{V_{mem}}{U_T}} (1 - e^{-\frac{V_{mem}}{U_T}})$$
(9)

thanks to I_{adap} the effect of a constant current applied to the neuron decreases with time, resulting in a decrease of the output firing rate that will affect the dynamics of the IOR mechanism.

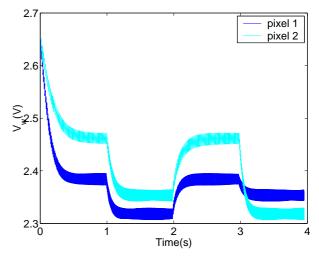


Figure 5. Synaptic weight of the two pixels. Pixel one is stimulated at 100Hz, then at 150Hz, 100Hz, 120Hz, pixel two receives 60Hz, 120Hz, 60Hz and eventually 150Hz. V_w depends on the absolute value of the frequency.

Results

Even the small two pixels network we simulated has an interesting dynamic behaviour enriched mostly by the introduction of the short term depression in the excitatory synapse. We stimulated the pixels with constant spike trains of different frequencies; the change in the synaptic weight depends on the input frequency as shown in Fig. 3. This effect is a useful feature that equalizes the inputs coming from noisy sources as spiking retinas [20]. This behaviour enhances responses to stimuli that change in time rather than to constant or slow stimuli. In Figure 5 and 6 we show the change in the synaptic weight and in the synaptic output current respectively for a 4 seconds simulation, where the frequency of the input spike trains changes every second: Pixel one is stimulated at 100Hz, then at 150Hz, 100Hz and 120Hz, while pixel two receives 60Hz, 120Hz, 60Hz and eventually 150Hz. The value of the synaptic weight depends on the absolute value of the frequency. The current peaks in correspondence to relative changes in the input: the synapse can be seen as an high pass filter, since it enhances the input's temporal variations. The output of this simulation is shown in Fig. 4. The network shows an even behaviour: after a transitory, due to the stimulus variation, it starts to switch between the most salient and the second most (less in our case) salient input, thanks to a balance between IOR and hysteresis.

CONCLUSIONS

In this paper we presented a neuromorphic device implementing a Winner–Take–All network. This device is designed to be a part of a multi–chip system for Selective Attention: via AER communication system it can be interfaced to silicon spiking reti-

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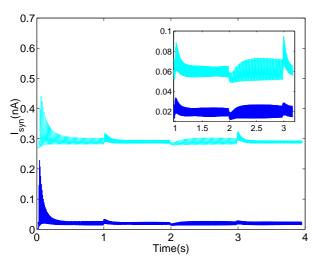


Figure 6. Synaptic output current, for the same simulation as in Fig. 5. The current shows peaks in correspondence of the stimulus variations, the amplitude of the peak is realated to the value of the input frequency step.

nas and to software implementations of associative memories.

We have shown that the new synaptic circuits can equalize the input to the competitive network, therefore it can cope with noisy inputs.

The prohibitive CPU simulation times for larger networks simulations didn't allow us to explore the possible additional features introduced by short term depression and spike frequency adaptation. The real time measurements allowed by the phisical realization of the chip are certainly a more powerful method to explore the network behaviour by changing its parameters.

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